MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Brodnet data speet

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VOLTAGE RANGE

150 to 200 Volts

CURRENT

3.0 Amperes





SMC

FEATURES

- * Ideal for surface mount applications
- * Easy pick and place
- * Built-in strain relief
- * Low forward voltage drop

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Metallurgically bonded construction
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.21 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

P/N(MARK)		SS315C	SS320C	UNITS
Maximum Recurrent Peak Reverse Voltage		150	200	V
Maximum RMS Voltage		105	140	V
Maximum DC Blocking Voltage		150	200	V
Maximum Average Forward Rectified Curre	nt			
at TL=100°C		3.0		Α
Peak Forward Surge Current, 8.3 ms single half sine-wave				
superimposed on rated load (JEDEC method)		80		Α
Maximum Instantaneous Forward Voltage at 3.0A		0.92		V
Maximum DC Reverse Current	Ta=25°C	0.	02	mA
at Rated DC Blocking Voltage	Ta=100°C	2	2	mA
Typical Junction Capacitance (Note1)		250		PF
Typical Thermal Resistance RθJL (Note 2)		10		°C/W
Operating Temperature Range T _J		-65 —+175		°C
Storage Temperature Range Tsтс		-65 —+175		°C

NOTES:

- 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 2. Thermal Resistance Junction to Lead Vertical PC Board Mounting 0.5"(12.7mm) Lead Length.



RATING AND CHARACTERISTIC CURVES (SS315C THRU SS320C)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

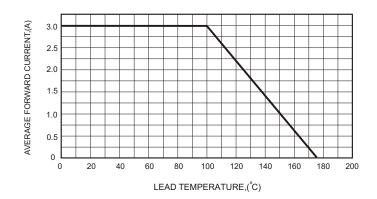


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

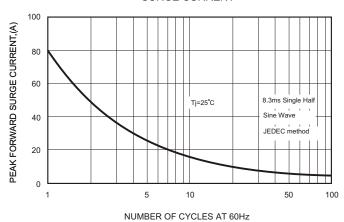


FIG.4-TYPICAL JUNCTION CAPACITANCE

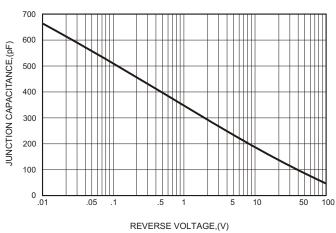


FIG.2-TYPICAL FORWARD

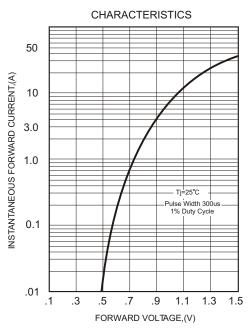
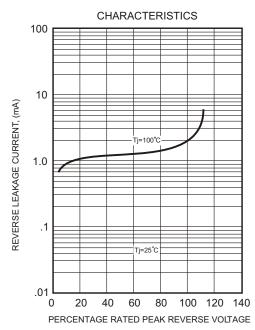
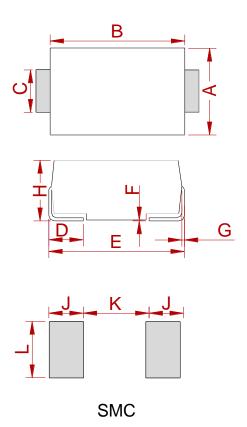


FIG.5 - TYPICAL REVERSE



PACKAGE MECHANICAL DATA



	Dimensions				
Ref.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	5.75	6.25	0.226	0.246	
В	6.90	7.40	0.272	0.291	
С	2.75	3.25	0.108	0.128	
D	0.95	1.52	0.037	0.060	
E	7.70	8.20	0.303	0.323	
F	0.051	0.203	0.002	0.008	
G	0.15	0.31	0.006	0.012	
Н	2.15	2.62	0.085	0.103	
J	2.40		0.094		
K		4.20		0.165	
L	3.30		0.130		

REEL SPECIFICATION

P/N	PKG	QTY
SS315C THRU SS320C	SMC	3000



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